

JW7721AH

100V, 10mΩ Synchronous Rectifier

Preliminary Specifications Subject to Change without Notice

DESCRIPTION

JW®7721AH is a synchronous rectifier, used for the secondary side rectification of isolation topologies, such as Active Clamp Flyback and CCM/QR/DCM Flyback. JW7721AH is able to significantly improve the efficiency comparing with the conventional Diode rectifier.

When JW7721AH senses V_{ds} of MOSFET less than -140mV, it turns on the internal MOSFET. Once the V_{ds} is greater than -6mV, JW7721AH turns off the internal MOSFET.

JW7721AH supports multiple operation modes, such as DCM, CrCM, CCM and Quasi-Resonant. By implementing the Joulwatt proprietary technology, JW7721AH is able to handle CCM operation.

JW7721AH is available in SOP-8 package.

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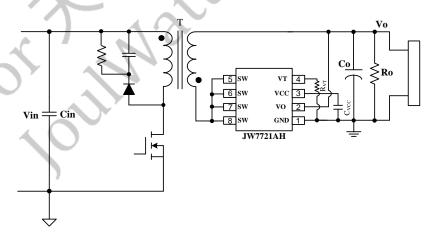
FEATURES

- Supports Active Clamp Flyback, DCM, Quasi-Resonant, and CCM Flyback
- Support High-side and Low-side Rectification
- Output Voltage Directly Supply VCC
- Low Quiescent Current
- Fast Driver Capability for CCM Operation
- SOP-8 Package

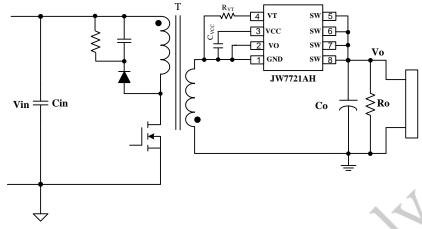
APPLICATIONS

- Active Clamp Flyback and Flyback Converters
- Adaptor
- LCD and PDP TV

TYPICAL APPLICATION



JW7721AH Typical Application for Low-side



JW7721AH Typical Application for High-side,

ORDER INFORMATION

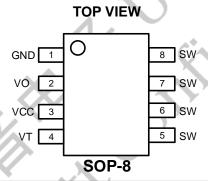
DEVICE ¹⁾	PACKAGE	TOP MARKING ²⁾	ENVIRONMENTAL ³⁾	
JW7721AHSOPB#TR	SOP8	JW7721AH	Green	
		YW□□□□□		

Notes:



3) All Joulwatt products are packaged with Pb-free and Halogen-free materials and compliant to RoHS standards.

PIN CONFIGURATION



ABSOLUTE MAXIMUM RATING1)

1 to 100V
0.3 to 28V
0.3 to 9V
0.3 to 7V
150°C
260°C
65°C to150°C
1W
2kV

RECOMMENDED OPERATING CONDITIONS

SW Pin	4.7	V to 80V
VO Pin	4.7	√ to 25V
VCC PIN	4\	/ to 8.5V
Operation Junction Temperature(T _J)	40°C	to 125°C
THERMAL PERFORMANCE ⁵⁾	$ heta_{J\!A}$	$ heta_{Jc}$
SOP-8	120	60°C/W

Note:

- 1) Exceeding these ratings may damage the device. These stress rating do not imply function operation of the device at any other conditions beyond those indicated under RECOMMENDED OPERATING CONDITIONS.
- 2) Continuous operation over the specified absolute maximum operating junction temperature may damage the device.
- 3) The device is not guaranteed to function outside of its operating conditions.
- 4) The maximum allowable continuous power dissipation at any ambient temperature is calculated by $P_D(MAX)=(T_J(MAX)-T_A)/\theta_{JA}$.
- 5) Measured on JESD51-7, 4-layer PCB

ELECTRICAL CHARACTERISTICS

TA = 25°C, unless otherwise stated						
Item	Symbol	Condition	Min.	Тур.	Max.	Units
VCC Section						
VCC Voltage	VCC	SW=40V, VCC=2.2uF	7.4	7.9	8.4	V
VCC Startup Voltage	V _{CC_Startup}		4.2	4.5	4.8	V
VCC UVLO	Vcc_uvlo		3.7	3.95	4.2	V
Operation Current (GT On)	lvcc	GT=5nF,VCC=2.2uF	0.65	1.05	1.35	mA
Quiescent Current	Iq	VCC=4.5V, VCC=2.2uF	100	125	140	uA
SW and VO Section						
Internal MOS Turn on Threshold	V _{MOS_ON}		-170	-140	-110	mV
Internal MOS Turn off Threshold	VMOS_OFF	100	/	-6		mV
Internal MOS Minimum on Time	T _{MIN_ON}	1/3		575		ns
Turn-on Total Delay 6)	T _{DON}	1.	76	50		nS
Turn-off Total Delay 6)	T_{DOF}	/ X C.	Ò	20		nS
VCC Charge Current	Isw_chg	SW=40V, VCC=6V	75	95		mA
VO Enable Charge Voltage	V _{O_EN}	VCC=4V, SW=0V, rising	4.48	4.6	4.8	V
VO Disable Charge Voltage	Vo_dis	VCC=4V, SW=0V, falling	4.4	4.55	4.7	V
VO Charge Current	lvo_cнg	SW=0V, VCC=6V, VO=12V	28	40	52	mA
Internal MOSFET Section						
Internal MOSFET Rdson	Rdson	VGT=10V		10		$m\Omega$
Breakdown Voltage	B _{(BR)DSS}		100			V

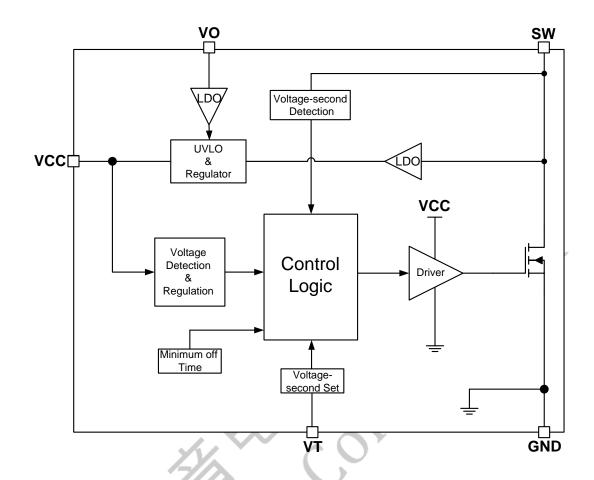
Note:
6) Guaranteed by design.

JW7721AH

PIN DESCRIPTION

Pin	Name	Description
1	GND	Ground.
2	VO	Output voltage sensing and charging to VCC.
3	VCC	Power supply. Bypass a capacitor between VCC and GND.
4	VT	Set the voltage-second product.
5,6,7,8	SW	Internal power MOSFET drain. Charging to VCC.

BLOCK DIAGRAM



FUNCTIONAL DESCRIPTION

Operation

JW7721AH is a synchronous rectifier combined with internal MOSFET can replace the Schottky Barrier Diode. It supports all operations, such as DCM, CrCM, (Quasi-Resonant) and CCM when adopted in Active Clamp Flyback and Flyback converters.

Startup

During the startup period, when the VCC is charged up by the two internal LDOs connected to SW and VO pin respectively.

When VO is lower than V_{O_EN} (falling), JW7721AH can power itself through the internal LDO connected to SW pin during the SR turn-off period, which means primary the primary side MOSFET is turned on and SW presents a positive voltage. A capacitor between VCC and GND is required to store the energy and supply to IC during the SR turn-on period.

When VO is above Vo_EN (rising), the VO pin charges VCC pin.

Once the VCC voltage exceeds $V_{\text{CC_Startup}}$, the JW7721AH exits the UVLO. If VCC is lower than $V_{\text{CC_UVLO}}$, the internal MOSFET is turned off. The current flows though body diode before the VCC reaches to the startup voltage $V_{\text{CC_startup}}$.

Under-Voltage Lockout (UVLO)

When the VCC is below UVLO threshold, the internal MOSFET is turned off and pulled low internally. Once the VCC exceeds the startup voltage Vcc_startup, the parts is activated again.

Turn On Phase

There are two conditions for the JW7721AH to turn on the internal MOSFET, i.e. V_{SW} ,

voltage-second value on SW pin when primary side switch is on, and the turn on phase is shown in Fig. 1.

- 1) V_{SW} : when the synchronous MOEFET is conducting, current flows through the body diode of MOSFET, which generates a negative voltage V_{SW} across it. When V_{SW} is lower than V_{MOS_ON} , the part will pull the gate high to turn on the synchronous MOSFET after turn on delay time T_{DON} if the other condition is met.
- 2) Volt-second of SW: in DCM and QR operation, there are parasitic oscillations. In some applications, the drain resonant voltage may fall below the SR turn on threshold, especially for the first couple rings. SR could be falsely turned on, which may cause shoot through issue and result in high power loss. The volt-second value of SW pin can be used to distinguish the parasitic ring from normal primary side switch on. The threshold can be set by the resistance at VT pin. The curve is shown in Fig. 2.

In application, as the output load(lo) of converter increases, the volt-second value(S1) of SW pin also increases. When the volt-second value(S1) of SW pin is greater than the high and gate turns on, the high threshold threshold becomes to low threshold. As the output load decreasing, when the gate turns off and the MOSFET bodydiode conduction time is no shorter than Ton_min., the low threshold becomes to the high threshold. When the Rvt is more than $250k\Omega$, the high threshold is fixed and the low threshold increases with the increasing of Rvt. The low threshold is fixed and equal to the high threshold when the Rvt is more than $330k \Omega$. The voltage-second hysteresis is shown in Fig. 2 and Fig. 3.

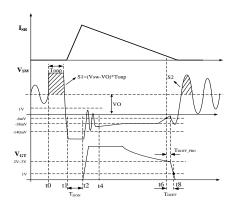


Fig. 1 Turn on delay and turn off delay

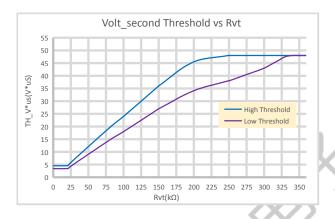


Fig. 2 Volt-second value vs. VT resistance

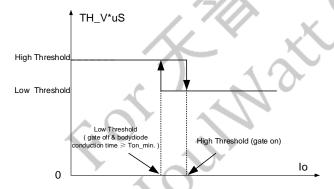


Fig. 3 Volt-second value with hysteresis

Minimum On Time (MOT)

When the synchronous MOSFET is turn on, there is a minimum on time for the SR. The V_{SW} voltage may have a parasitic ring when the synchronous MOSFET turns on. So, a minimum on time (MOT) is very important to avoid the MOSFET turn off threshold is false triggered.

Minimum on time is 575ns for high frequency applications.

Conducting Phase

When the synchronous MOSFET is turned on, the drain source voltage V_{SW} it is determined by its on resistance and the current through it. The part adjusts the gate voltage and regulates the V_{SW} to the internal threshold (typical -40mV) after the synchronous MOSFET turn on. When the V_{SW} is lower than -40mV, the gate keeps its maximum voltage. And the synchronous MOSFET is fully on.

The V_{SW} rises when the current follow through the MOSFET decreases. The gate voltage will be decreased to increase its on resistance and regulate the V_{SW} around -40mV.

It should be noted that the typical regulation threshold (-40mV) during MOSFET on time is not fixed, it can be internally changed to ensure the proper operation under CCM mode.

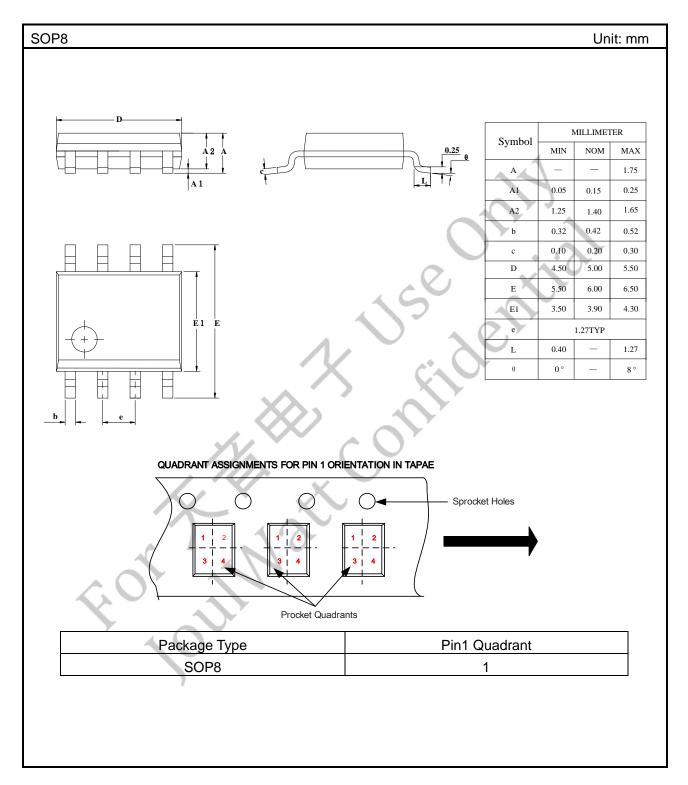
Turn Off Phase

After synchronous MOSFET conducting, once the voltage V_{SW} touches the MOSFET turn off threshold (-6mV), the gate is pulled to low after a turn off delay time T_{DOFF} . A 365nS blanking time is necessary to avoid error trigger. The banking time is reset once V_{SW} rises above +2.5V.

Output Voltage Detection

The JW7721AH has output voltage detection function via VO pin. VCC is charged from VO pin when VO is higher than Vo_EN to save power loss caused by the LDO when charging from SW pin to VCC pin. When VO drops below Vo_DIS, the JW7721AH is powered from SW pin.

PACKAGE OUTLINE



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